
HD74LV1GT14A

Inverter with Schmitt-trigger Input

HITACHI

ADE-205-329C (Z)
4th. Edition
April 2001

Description

The HD74LV1GT14A is high speed CMOS schmitt-trigger inverter using silicon gate CMOS process. With CMOS low power dissipation, it provides high speed equivalent to LS-TTL series. The internal circuit of three stages construction with buffer provides wide noise margin and stable output. Low voltage and high speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

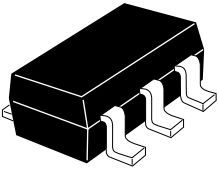
Features

- The basic gate function is lined up as hitachi uni logic series.
- Supplied on emboss taping for high speed automatic mounting.
- TTL compatible input level.
Supply voltage range : 4.5 to 5.5 V
Operating temperature range : -40 to +85°C
- All inputs V_{IH} (Max.) = 5.5 V (@ V_{CC} = 0 V to 5.5 V)
All outputs V_O (Max.) = 5.5 V (@ V_{CC} = 0 V)
- Output current ± 12 mA (@ V_{CC} = 4.5 V to 5.5 V)
- All the logical input has hysteresis voltage for the slow transition.

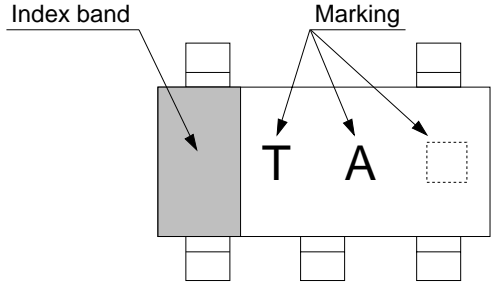
HD74LV1GT14A

Outline and Article Indication

- HD74LV1GT14A

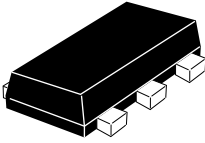


CMPAK-5

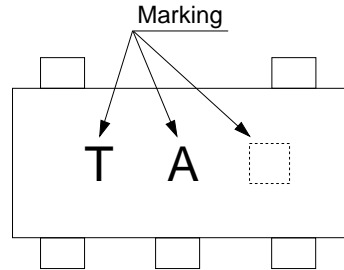


□ = Control code
(— or blank)

- HD74LV1GT14A



VSON-5



□ = Control code

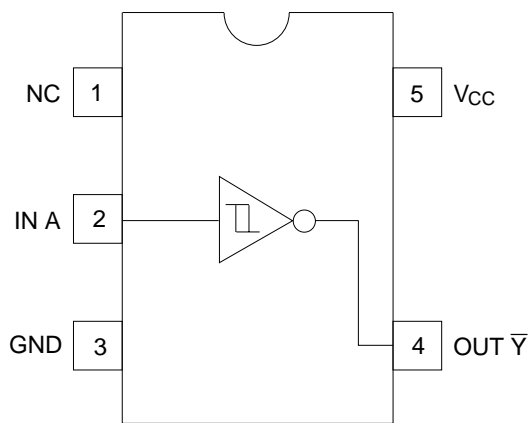
Function Table

| Input A | Output \bar{Y} |
|---------|------------------|
| H | L |
| L | H |

H : High level

L : Low level

Pin Arrangement



(Top view)

Absolute Maximum Ratings

| Item | Symbol | Ratings | Unit | Test Conditions |
|--|-----------------------|---------------------------------------|------------------|-----------------------------------|
| Supply voltage range | V_{CC} | -0.5 to 7.0 | V | |
| Input voltage range ^{*1} | V_I | -0.5 to 7.0 | V | |
| Output voltage range ^{*1,2} | V_O | -0.5 to $V_{CC} + 0.5$ -0.5 to 7.0 | V | Output : H or L V_{CC} : OFF |
| Input clamp current | I_{IK} | -20 | mA | $V_I < 0$ |
| Output clamp current | I_{OK} | ± 50 | mA | $V_O < 0$ or $V_O > V_{CC}$ |
| Continuous output current | I_O | ± 25 | mA | $V_O = 0$ to V_{CC} |
| Continuous current through V_{CC} or GND | I_{CC} or I_{GND} | ± 50 | mA | |
| Maximum power dissipation at $T_a = 25^\circ\text{C}$ (in still air) ^{*3} | P_T | 200 | mW | |
| Storage temperature | T_{stg} | -65 to 150 | $^\circ\text{C}$ | |

Notes: The absolute maximum ratings are values which must not individually be exceeded, and furthermore no two of which may be realized at the same time.

1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
2. This value is limited to 5.5 V maximum.
3. The maximum package power dissipation was calculated using a junction temperature of 150°C .

Recommended Operating Conditions

| Item | Symbol | Min | Max | Unit | Conditions |
|--------------------------------|----------|-----|----------|------------------|---------------------------|
| Supply voltage range | V_{CC} | 4.5 | 5.5 | V | |
| Input voltage range | V_I | 0 | 5.5 | V | |
| Output voltage range | V_O | 0 | V_{CC} | V | |
| Output current | I_{OL} | — | 12 | mA | $V_{CC} = 4.5$ to 5.5 V |
| | I_{OH} | — | -12 | | $V_{CC} = 4.5$ to 5.5 V |
| Operating free-air temperature | T_a | -40 | 85 | $^\circ\text{C}$ | |

Note: Unused or floating inputs must be held high or low.

Electrical Characteristic

- $T_a = -40$ to 85°C

| Item | Symbol | V_{CC} (V) * | Min | Typ | Max | Unit | Test condition |
|--------------------------|-----------------|----------------|--------------|-----|---------|---------------|---|
| Input voltage | V_T^+ | 4.5 | — | — | 1.9 | V | |
| | | 5.5 | — | — | 2.1 | | |
| | V_T^- | 4.5 | 0.5 | — | — | | |
| | | 5.5 | 0.6 | — | — | | |
| | ΔV_T | 4.5 | 0.4 | — | 1.4 | | |
| | | 5.5 | 0.4 | — | 1.5 | | |
| Output voltage | V_{OH} | Min to Max | $V_{CC}-0.1$ | — | — | V | $I_{OH} = -50 \mu\text{A}$ |
| | | 4.5 | 3.8 | — | — | | $I_{OH} = -12 \text{ mA}$ |
| | V_{OL} | Min to Max | — | — | 0.1 | | $I_{OL} = 50 \mu\text{A}$ |
| | | 4.5 | — | — | 0.55 | | $I_{OL} = 12 \text{ mA}$ |
| Input current | I_{IN} | 0 to 5.5 | — | — | ± 1 | μA | $V_{IN} = 5.5 \text{ V or GND}$ |
| Quiescent supply current | I_{CC} | 5.5 | — | — | 10 | μA | $V_{IN} = V_{CC}$ or GND, $I_O = 0$ |
| | ΔI_{CC} | 5.5 | — | — | 1.5 | mA | One input $V_{IN} = 3.4 \text{ V}$, other input V_{CC} or GND |
| Output leakage current | I_{OFF} | 0 | — | — | 5 | μA | V_{IN} or $V_O = 0$ to 5.5 V |
| Input capacitance | C_{IN} | 5.0 | — | 3.0 | — | pF | $V_{IN} = V_{CC}$ or GND |

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

Switching Characteristics

- $V_{CC} = 5.0 \pm 0.5$ V

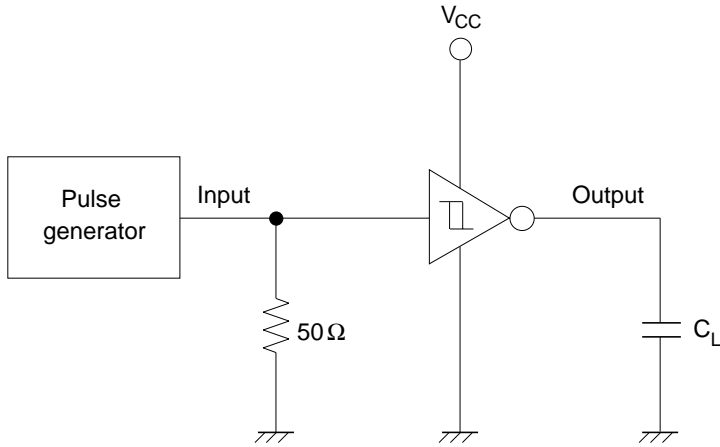
| Item | Symbol | $T_a = 25^\circ\text{C}$ | | | $T_a = -40$ to 85°C | | Unit | Test Conditions | FROM (Input) | TO (Output) |
|------------------------|-----------|--------------------------|-----|-----|-----------------------------------|------|------|-----------------|--------------|-------------|
| | | Min | Typ | Max | Min | Max | | | | |
| Propagation delay time | t_{PLH} | — | 5.0 | 7.6 | 1.0 | 9.0 | ns | $C_L = 15$ pF | A | \bar{Y} |
| | t_{PHL} | — | 6.5 | 9.6 | 1.0 | 11.0 | | $C_L = 50$ pF | | |

Operating Characteristics

- $C_L = 50$ pF

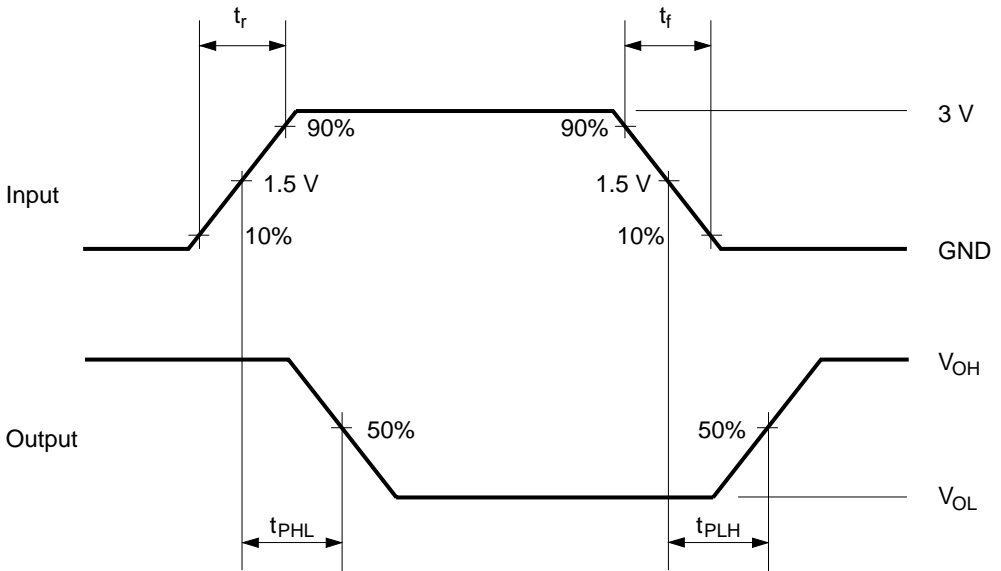
| Item | Symbol | V_{CC} (V) | $T_a = 25^\circ\text{C}$ | | | Unit | Test Conditions |
|-------------------------------|----------|--------------|--------------------------|------|-----|------|-----------------|
| | | | Min | Typ | Max | | |
| Power dissipation capacitance | C_{PD} | 5.0 | — | 10.0 | — | pF | $f = 10$ MHz |

Test Circuit



Note: C_L includes probe and jig capacitance.

• Waveforms

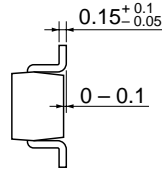
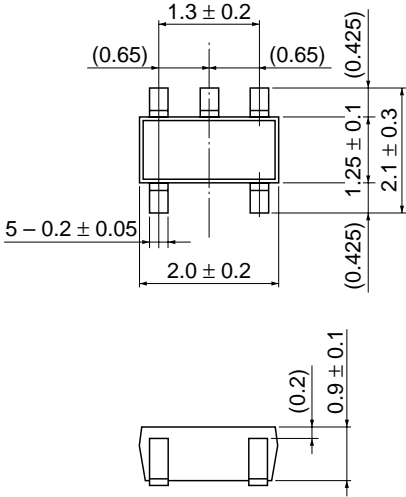


- Notes: 1. Input waveform : PRR \leq 1 MHz, $Z_o = 50 \Omega$, $t_r \leq 3$ ns, $t_f \leq 3$ ns.
 2. The output are measured one at a time with one transition per measurement.

Package Dimensions

As of January, 2001

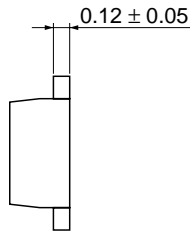
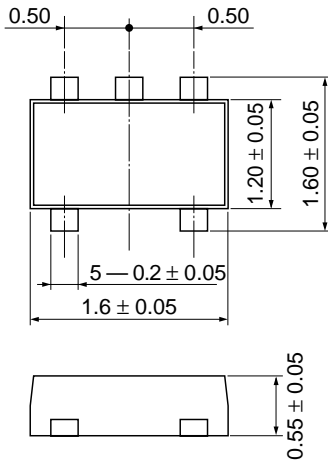
Unit: mm



| | |
|------------------------|----------|
| Hitachi Code | CMPAK-5 |
| JEDEC | — |
| EIAJ | Conforms |
| Mass (reference value) | 0.006 g |

As of January, 2001

Unit: mm



| | |
|------------------------|--------|
| Hitachi Code | TNP-5D |
| JEDEC | — |
| EIAJ | — |
| Mass (reference value) | — |

Cautions

1. Hitachi neither warrants nor grants licenses of any rights of Hitachi's or any third party's patent, copyright, trademark, or other intellectual property rights for information contained in this document. Hitachi bears no responsibility for problems that may arise with third party's rights, including intellectual property rights, in connection with use of the information contained in this document.
2. Products and product specifications may be subject to change without notice. Confirm that you have received the latest product standards or specifications before final design, purchase or use.
3. Hitachi makes every attempt to ensure that its products are of high quality and reliability. However, contact Hitachi's sales office before using the product in an application that demands especially high quality and reliability or where its failure or malfunction may directly threaten human life or cause risk of bodily injury, such as aerospace, aeronautics, nuclear power, combustion control, transportation, traffic, safety equipment or medical equipment for life support.
4. Design your application so that the product is used within the ranges guaranteed by Hitachi particularly for maximum rating, operating supply voltage range, heat radiation characteristics, installation conditions and other characteristics. Hitachi bears no responsibility for failure or damage when used beyond the guaranteed ranges. Even within the guaranteed ranges, consider normally foreseeable failure rates or failure modes in semiconductor devices and employ systemic measures such as fail-safes, so that the equipment incorporating Hitachi product does not cause bodily injury, fire or other consequential damage due to operation of the Hitachi product.
5. This product is not designed to be radiation resistant.
6. No one is permitted to reproduce or duplicate, in any form, the whole or part of this document without written approval from Hitachi.
7. Contact Hitachi's sales office for any questions regarding this document or Hitachi semiconductor products.

HITACHI

Hitachi, Ltd.

Semiconductor & Integrated Circuits.
Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan
Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

URL NorthAmerica : <http://semiconductor.hitachi.com/>
 Europe : <http://www.hitachi-eu.com/hel/ecg>
 Asia : <http://sicapac.hitachi-asia.com>
 Japan : <http://www.hitachi.co.jp/Sicd/indx.htm>

For further information write to:

Hitachi Semiconductor (America) Inc.
179 East Tasman Drive,
San Jose, CA 95134
Tel: <1> (408) 433-1990
Fax: <1> (408) 433-0223

Hitachi Europe Ltd.
Electronic Components Group.
Whitebrook Park
Lower Cookham Road
Maidenhead
Berkshire SL6 8YA, United Kingdom
Tel: <44> (1628) 585000
Fax: <44> (1628) 585200

Hitachi Europe GmbH
Electronic Components Group
Dornacher Straße 3
D-85622 Feldkirchen, Munich
Germany
Tel: <49> (89) 9 9180-0
Fax: <49> (89) 9 29 30 00

Hitachi Asia Ltd.
Hitachi Tower
16 Collyer Quay #20-00,
Singapore 049318
Tel : <65>-538-6533/538-8577
Fax : <65>-538-6933/538-3877
URL : <http://www.hitachi.com.sg>

Hitachi Asia Ltd.
(Taipei Branch Office)
4/F, No. 167, Tun Hwa North Road,
Hung-Kuo Building,
Taipei (105), Taiwan
Tel : <886>-(2)-2718-3666
Fax : <886>-(2)-2718-8180
Telex : 23222 HAS-TP
URL : <http://www.hitachi.com.tw>

Hitachi Asia (Hong Kong) Ltd.
Group III (Electronic Components)
7/F., North Tower,
World Finance Centre,
Harbour City, Canton Road
Tsim Sha Tsui, Kowloon,
Hong Kong
Tel : <852>-(2)-735-9218
Fax : <852>-(2)-730-0281
URL : <http://semiconductor.hitachi.com.hk>

Copyright © Hitachi, Ltd., 2001. All rights reserved. Printed in Japan.

Colophon 3.0